# Schottky barrier diode

## RB751S-40 / RB751V-40

#### Applications

High speed switching For Detection

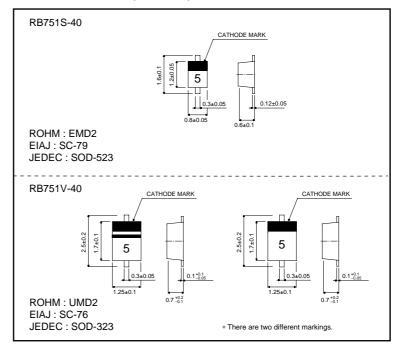
### ● Features

- Small surface mounting type. (EMD2, UMD2)
- 2) Low reverse current and low forward voltage.
- 3) High reliability.

#### Construction

Silicon epitaxial planar

#### ●External dimensions (Units : mm)



### ● Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Limits	Unit
Peak reverse voltage	V <sub>RM</sub>	40	V
DC reverse voltage	VR	30	V
Mean rectifying current	lo	30	mA
Peak forward surge current*	<b>I</b> FSM	200	mA
Junction temperature	Tj	125	°C
Storage temperature	Tstg	-40~+125	°C

<sup>\* 60</sup> Hz for 1  $\sim$ 

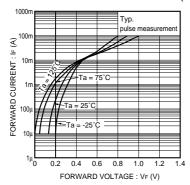
### ●Electrical characteristics (Ta = 25°C)

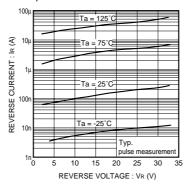
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	VF	_	_	0.37	V	IF = 1mA
Reverse current	IR	_	_	0.5	μΑ	V <sub>R</sub> = 30V
Capacitance between terminals	Ст	_	2.0	_	pF	V <sub>R</sub> = 1V, f = 1MHz

Note) ESD sensitive product handling required.



### ●Electrical characteristic curves (Ta = 25°C)





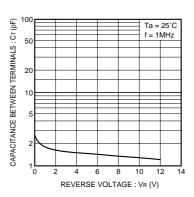


Fig. 1 Forward characteristics

Fig. 2 Reverse characteristics

Fig. 3 Capacitance between terminals characteristics

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